

## 4A, 50V - 1000V Surface Mount Rectifier

### FEATURES

- Glass passivated chip junction
- Ideal for automated placement
- Low forward voltage drop
- High current capability
- High surge current capability
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

### APPLICATIONS

- Switching mode power supply (SMPS)
- Adapters
- Lighting application
- Converter

### MECHANICAL DATA

- Case: DO-214AB (SMC)
- Molding compound meets UL 94V-0 flammability rating
- Part no. with suffix "H" means AEC-Q101 qualified
- Packing code with suffix "G" means green compound (halogen-free)
- Moisture sensitivity level: level 1, per J-STD-020
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 2 whisker test
- Polarity: As marked
- Weight: 0.21 g (approximately)

KEY PARAMETERS		
PARAMETER	VALUE	UNIT
$I_{F(AV)}$	4	A
$V_{RRM}$	50 - 1000	V
$I_{FSM}$	100	A
$T_{J\ MAX}$	150	°C
Package	DO-214AB (SMC)	
Configuration	Single die	



**DO-214AB (SMC)**

ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^\circ\text{C}$ unless otherwise noted)									
PARAMETER	SYMBOL	S4A	S4B	S4D	S4G	S4J	S4K	S4M	UNIT
Marking code on the device		S4A	S4B	S4D	S4G	S4J	S4K	S4M	
Repetitive peak reverse voltage	$V_{RRM}$	50	100	200	400	600	800	1000	V
Reverse voltage, total rms value	$V_{R(RMS)}$	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	$V_{DC}$	50	100	200	400	600	800	1000	V
Forward current	$I_{F(AV)}$	4							A
Surge peak forward current, 8.3 ms single half sine-wave superimposed on rated load per diode	$I_{FSM}$	100							A
Junction temperature	$T_J$	- 55 to +150							°C
Storage temperature	$T_{STG}$	- 55 to +150							°C

**THERMAL PERFORMANCE**

PARAMETER	SYMBOL	TYP	UNIT
Junction-to-lead thermal resistance per diode	$R_{\theta JL}$	13	°C/W
Junction-to-ambient thermal resistance per diode	$R_{\theta JA}$	47	°C/W

**ELECTRICAL SPECIFICATIONS** ( $T_A = 25^\circ\text{C}$  unless otherwise noted)

PARAMETER	CONDITIONS	SYMBOL	TYP.	MAX.	UNIT
Forward voltage per diode <sup>(1)</sup>	$I_F = 4\text{A}$ , $T_J = 25^\circ\text{C}$	$V_F$	-	1.15	V
Reverse current @ rated $V_R$ per diode <sup>(2)</sup>	$T_J = 25^\circ\text{C}$	$I_R$	-	10	$\mu\text{A}$
	$T_J = 125^\circ\text{C}$		-	250	$\mu\text{A}$
Junction capacitance	1 MHz, $V_R = 4.0\text{V}$	$C_J$	60	-	pF
Reverse recovery time	$I_F = 0.5\text{A}$ , $I_R = 1.0\text{A}$ $I_{RR} = 0.25\text{A}$	$t_{rr}$	1500	-	ns

**Notes:**

1. Pulse test with  $PW = 0.3\text{ ms}$
2. Pulse test with  $PW = 30\text{ ms}$

**ORDERING INFORMATION**

PART NO.	PART NO. SUFFIX	PACKING CODE	PACKING CODE SUFFIX	PACKAGE	PACKING
S4A (Note 1,2)	H	R7	G	SMC	850 / 7" Plastic reel
		R6		SMC	3,000 / 13" Paper reel
		M6		SMC	3,000 / 13" Plastic reel
		V7		Matrix SMC	850 / 7" Plastic reel
		V6		Matrix SMC	3,000 / 13" Plastic reel

**Note :**

1. "x" defines voltage from 50V (S4A) to 1000V (S4M)
2. Only V6 and V7 are all green compound (halogen free)

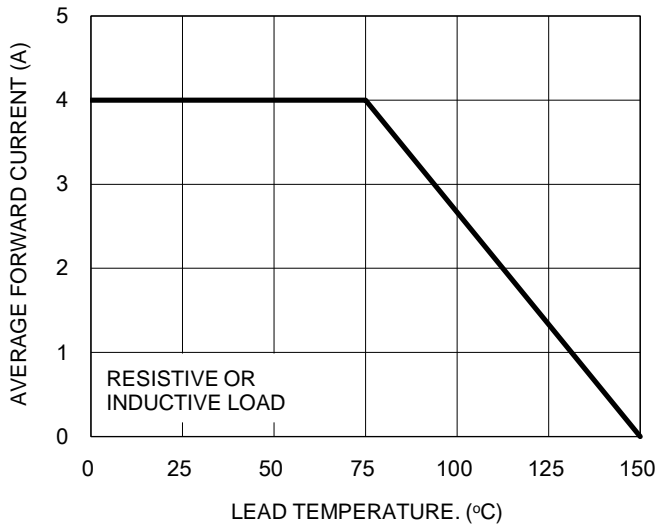
**EXAMPLE**

EXAMPLE P/N	PART NO.	PART NO. SUFFIX	PACKING CODE	PACKING CODE SUFFIX	DESCRIPTION
S4AHR7G	S4A	H	R7	G	AEC-Q101 qualified Green compound

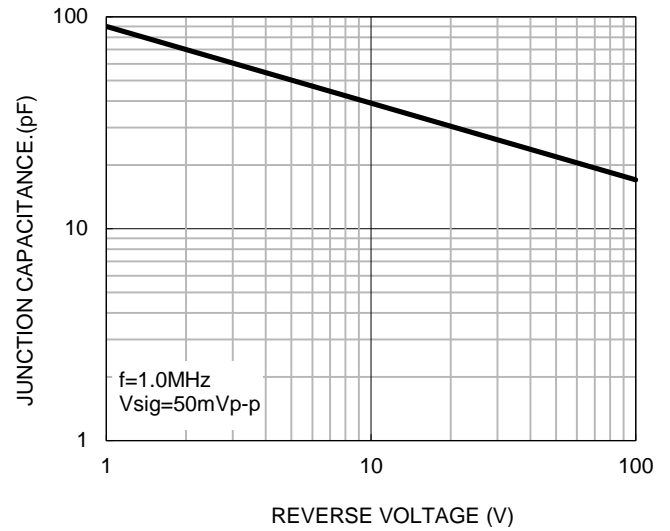
## CHARACTERISTICS CURVES

( $T_A = 25^\circ\text{C}$  unless otherwise noted)

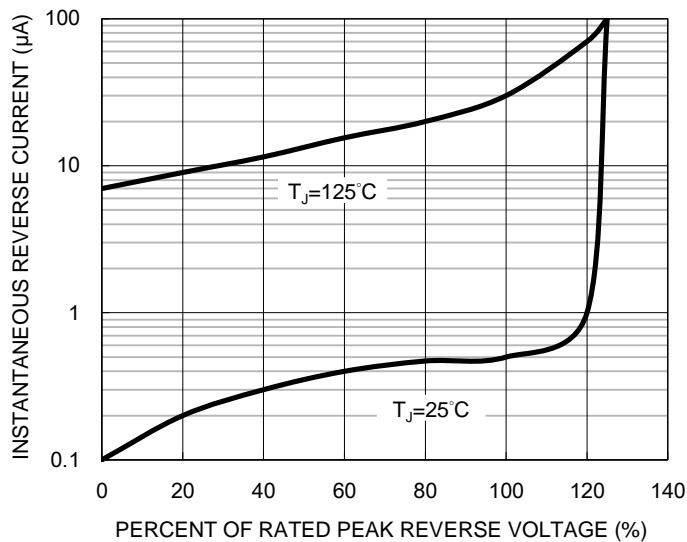
**Fig.1 Forward Current Derating Curve**



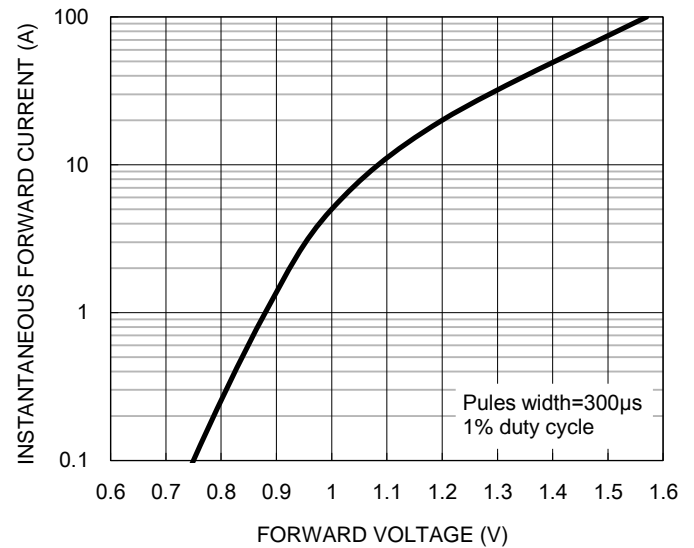
**Fig.2 Typical Junction Capacitance**



**Fig.3 Typical Reverse Characteristics**



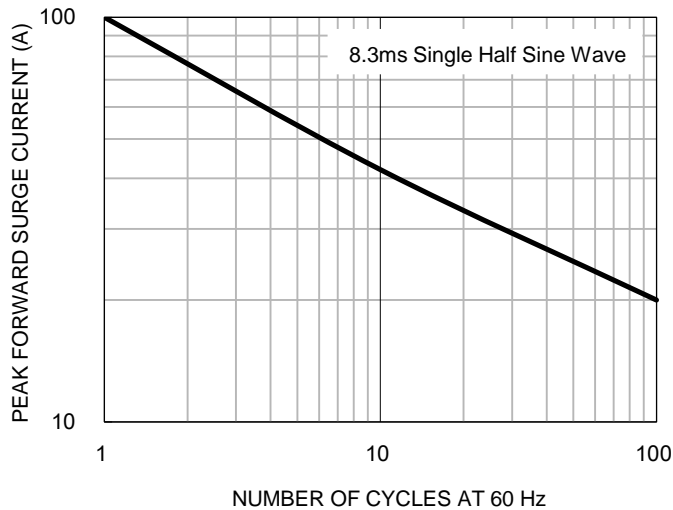
**Fig.4 Typical Forward Characteristics**



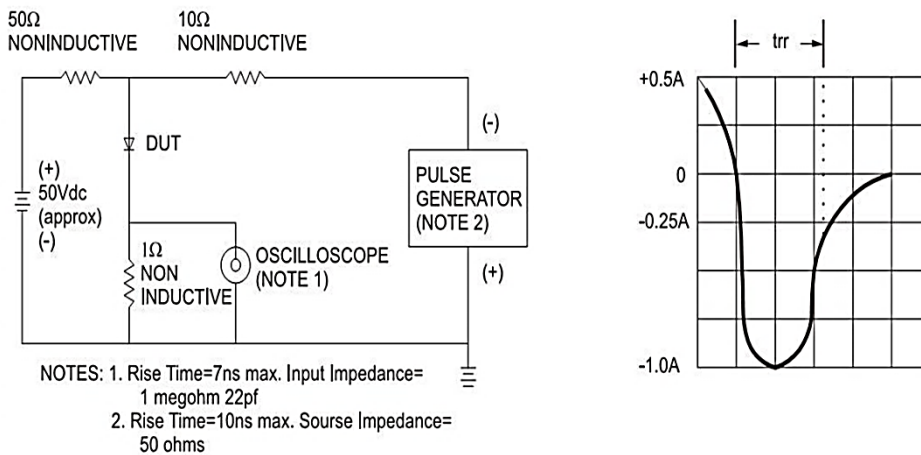
## CHARACTERISTICS CURVES

( $T_A = 25^\circ\text{C}$  unless otherwise noted)

**Fig.5 Maximum Non-repetitive Forward Surge Current**

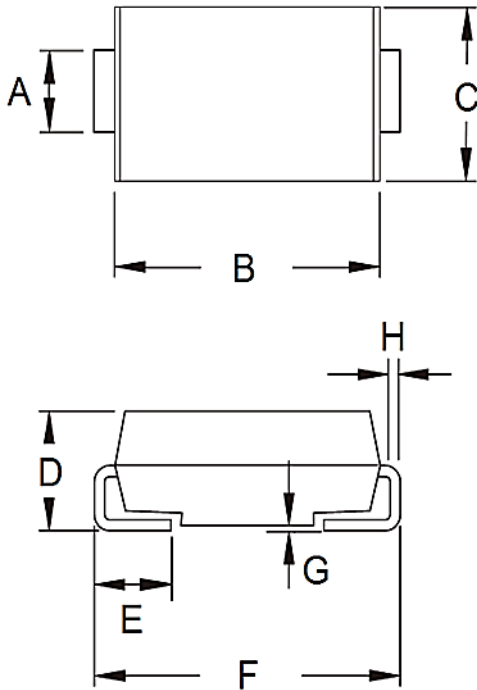


**Fig.6 Reverse Recovery Time Characteristic And Test Circuit Diagram**



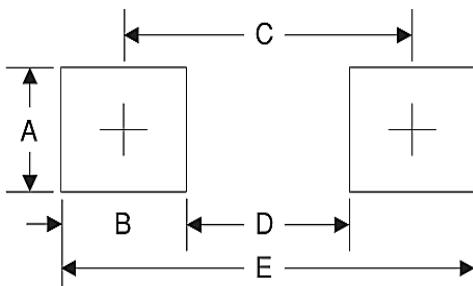
## PACKAGE OUTLINE DIMENSIONS

DO-214AB (SMC)



DIM.	Unit (mm)		Unit (inch)	
	Min.	Max.	Min.	Max.
A	2.90	3.20	0.114	0.126
B	6.60	7.11	0.260	0.280
C	5.59	6.22	0.220	0.245
D	2.00	2.62	0.079	0.103
E	1.00	1.60	0.039	0.063
F	7.75	8.13	0.305	0.320
G	0.10	0.20	0.004	0.008
H	0.15	0.31	0.006	0.012

## SUGGESTED PAD LAYOUT



Symbol	Unit (mm)	Unit (inch)
A	3.30	0.130
B	2.50	0.098
C	6.80	0.268
D	4.40	0.173
E	9.40	0.370

## MARKING DIAGRAM

Matrix SMC



SMC



P/N =Marking Code  
G =Green Compound  
YW =Date Code  
F =Factory Code

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